



### AH1381/AH1382/AH1383

### HIGH-SENSITIVITY ULTRA-LOW POWER DIGITAL UNIPOLAR HALL-EFFECT SWITCH

## Description

The AH1381/AH1382/AH1383 is an ultra-low power digital Unipolar Hall-effect switch IC from Diodes Incorporated's broad Hall-effect switches family. Thanks to the hibernating clocking system, the average supply current is only  $1.6\mu$ A at 3V, which makes the AH1381/AH1382/AH1383 perfectly fit battery-powered consumer products, gas or water meters, smoke detectors and IoT devices. The wider range of the supply voltage (1.6V to 5.5V) extends battery operating time and supports low-voltage system microcontrollers, which provides great flexibility for system design. The advanced chopper stabilized design provides superior stability on switch operating point over temperature and supply voltage. The high ESD level up to 8kV helps to improve the system robustness.

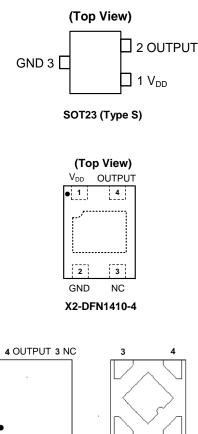
The output is activated with south pole of sufficient magnetic field strength. When the magnetic flux density (B) perpendicular to the package is larger than operate point (BoPs), the output will be turned on (pulled low) and held until B is lower than release point (BRPS).

The devices are packaged in SOT23 (Type S) and small low profile X2-DFN1410-4 and X2-DFN1010-4 (Type B).

### Features

- Unipolar Operation (South Pole)
- Supply Voltage of 1.6V to 5.5V
- Micro Power Operation
- Chopper Stabilized Design Provides:
  - Superior Temperature Stability
  - Minimal Switch Point Drift
  - Enhanced Immunity to Physical Stress
- No External Pullup Resistors Required
- Good RF Noise Immunity
- -40°C to +85°C Operating Temperature
- High ESD Capability of 8kV (Human Body Model)
- Small Low Profile SOT23 (Type S), X2-DFN1410-4 and X2-DFN1010-4 (Type B) Packages
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>





X2-DFN1010-4 (Type B)

2

**Bottom View** 

2 GND

### Applications

- Smart covers for cellular phones, tablets, laptops, Chromebooks
- Open and close detect for TWS, digital still/video cameras and handheld gaming consoles
- Medical devices, IoT systems

1 V<sub>DD</sub>

Top View

- Level, proximity and position switches
- E-locks, smoke detectors, appliances
- Doors, lids and tray position switches
- Home appliances such as washing machines, refrigerators
- Industrial applications such as smart meters, E-meters, power tools

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

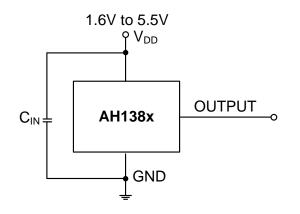
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  - 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

Notes:

# 9



# **Typical Applications Circuit**



Note: 4. C<sub>IN</sub> is for power stabilization and to strengthen the noise immunity, the recommended capacitance is 100nF typical and should be placed as close to the supply pin as possible.

# **Pin Descriptions**

### (1) Package: SOT23 (Type S)

Pin Number	Pin Name	Function
1	Vdd	Power Supply Input
2	OUTPUT	Output Pin
3	GND	Ground Pin

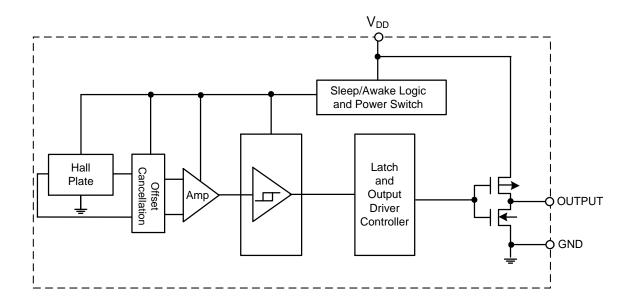
#### (2) Packages: X2-DFN1410-4, X2-DFN1010-4 (Type B)

Pin Number	Pin Name	Function
1	V <sub>DD</sub>	Power Supply Input
2	GND	Ground Pin
3	NC	No Connection (Note 5)
4	OUTPUT	Output Pin
Pad	Pad	The center exposed pad – No connection internally. The exposed pad can be left open (unconnected to) on the PCB layout.

Note: 5. NC is "No Connection" pin and is not connected internally. This pin can be left open or tied to ground.



## **Functional Block Diagram**



### Absolute Maximum Ratings (Note 6) (@TA = +25°C, unless otherwise specified.)

Symbol	Р	Rating	Unit	
Vdd	Supply Voltage (Note 7)		6	V
Vdd_rev	Reverse Supply Voltage		-0.3	V
IOUTPUT	Output Current (Source and Sink)		1	mA
В	Magnetic Flux Density		Unlimited	
6	Deckere Deven Dissinction	SOT23 (Type S) and X2-DFN1410-4	230	
PD	Package Power Dissipation	X2-DN1010-4 (Type B)	400	mW
Ts	Storage Temperature Range		-65 to +150	°C
TJ	Maximum Junction Temperature		+150	°C
ESD HBM	Human Body Model (HBM) ESD Cap	ability	8	kV

Notes: 6. Stresses greater than those listed under Absolute Maximum Ratings can cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to Absolute Maximum Ratings for extended periods can affect device reliability.

7. The absolute maximum V<sub>DD</sub> of 6V is a transient stress rating and is not meant as a functional operating condition. It is not recommended to operate the device at the absolute maximum rated conditions for any period of time.

# Recommended Operating Conditions (@TA = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Rating	Unit
V <sub>DD</sub>	Supply Voltage	Operating	1.6V to 5.5V	V
TA	Operating Temperature Range	Operating	-40 to +85	°C

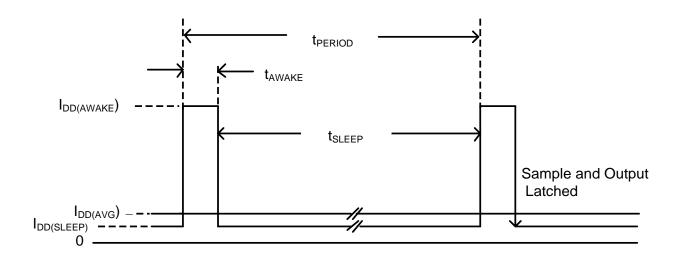


# Electrical Characteristics (@TA = +25°C, VDD = 3V, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>OL</sub>	Output Low Voltage (On)	I <sub>OUT</sub> = 1mA	_	0.15	0.25	V
V <sub>OH</sub>	Output High Voltage (Off)	I <sub>OUT</sub> = -1mA	V <sub>DD</sub> -0.25	V <sub>DD</sub> -0.15	_	V
	Cumply Cumpet	T <sub>A</sub> = +25°C, V <sub>DD</sub> = 3V	_	1	1.5	mA
IDD(AWAKE) Supply Current	Supply Current	$T_A = -40$ to +85°C, $V_{DD} = 1.6V$ to 5.5V	_	1	3	mA
IDD(SLEEP) Supply Current	$T_A = +25^{\circ}C, V_{DD} = 3V$	_	0.6	1	μA	
	$T_A = -40$ to +85°C, $V_{DD} = 1.6V$ to 5.5V	_	0.6	3	μA	
		T <sub>A</sub> = +25°C, V <sub>DD</sub> = 3V	_	1.6	3	μA
IDD(AVG)	Average Supply Current	$T_A = -40$ to $+85^{\circ}$ C, $V_{DD} = 1.6$ V to $5.5$ V (Note 8)	_	1.6	9	μA
<b>t</b> AWAKE	Awake Time	(Note 9)	30	45	80	μs
<b>t</b> PERIOD	Period	(Note 9)	30	45	80	ms
D.C.	Duty Cycle	_	—	0.1	_	%

Notes:

Typical data is at T<sub>A</sub> = +25°C, V<sub>DD</sub> = 3V.
When power is initially turned on, the operating V<sub>DD</sub> (1.6V to 5.5V) must be applied to guaranteed the output sampling. The output state is valid after the second operating cycle (typical 90ms).

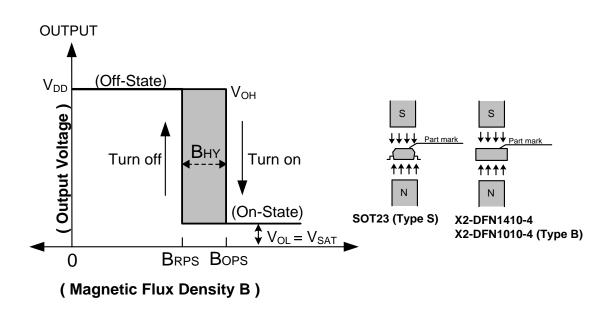




						(1mT=10	Gauss)
Part Number	Symbol	Parameter	Condition	Min	Тур	Max	Unit
		Operating Daint	T <sub>A</sub> = +25°C	10	18	26	
	B <sub>OPS</sub> (South Pole to Part Marking Side)	Operating Point	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	6	18	30	
AH1381	Den a (Cauth Dala ta Dart Marking Cida)	Delegging Deint	T <sub>A</sub> = +25°C	3	11	19	Gauss
	BRPS (South Pole to Part Marking Side)	Releasing Point	T <sub>A</sub> = -40°C to +85°C	2	11	24	
	Bhy ( Bops - Brps )	Hysteresis	(Note 10)	2	7	_	
	BOPS (South Pole to Part Marking Side)	Operating Point	T <sub>A</sub> = +25°C	22	30	38	
			$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	18	30	42	
AH1382		Releasing Point	T <sub>A</sub> = +25°C	12	20	30	Gauss
	B <sub>RPS</sub> (South Pole to Part Marking Side)		$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	8	20	33	
	Bhy ( Bops - Brps )		(Note 10)	2	10	_	
	Deve (Couth Delete Dest Marking Cide)	Operating Point	T <sub>A</sub> = +25°C	35	45	55	
	BOPS (South Pole to Part Marking Side)		T <sub>A</sub> = -40°C to +85°C	25	45	60	
AH1383		Releasing Point	T <sub>A</sub> = +25°C	25	35	45	Gauss
	B <sub>RPS</sub> (South Pole to Part Marking Side)		$T_A = -40^{\circ}C$ to $+85^{\circ}C$	20	35	55	1
	Bhy ( Bops - Brps )	Hysteresis	(Note 10)	2	10	_	1

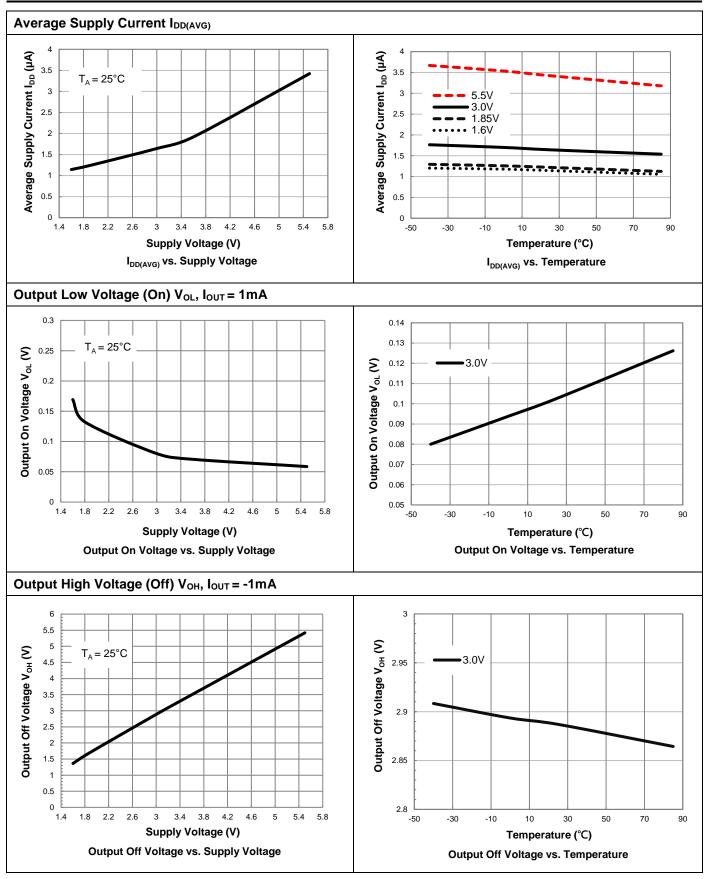
### Magnetic Characteristics (Note 10) (TA = +25°C, VDD = 3V, unless otherwise specified.)

Note: 10. Maximum and minimum parameters values over operating temperature range are not tested in production, they are guaranteed by design, characterization and process control. The magnetic characteristics may vary with supply voltage, operating temperature and after soldering.



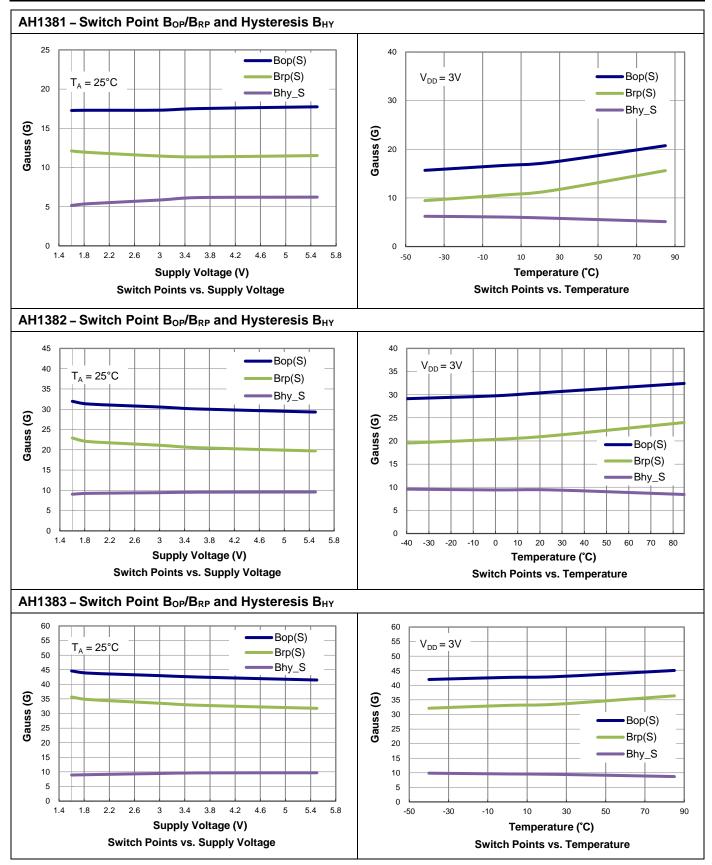


# **Typical Operating Characteristics**



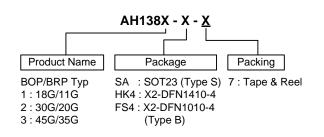


# Typical Operating Characteristics (continued)





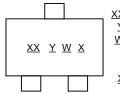
### **Ordering Information**



Port Number	Part Number Part Number Suffix Package Code Package	Pac	king		
Fart Number	Fart Number Sumx	Package Code	Гаскауе	Qty.	Carrier
AH138X-SA-7	-7	SA	SOT23 (Type S)	3000	7" Tape & Reel
AH138X-HK4-7	-7	HK4	X2-DFN1410-4	4000	7" Tape & Reel
AH138X-FS4-7	-7	FS4	X2-DFN1010-4 (Type B)	5000	7" Tape & Reel

### **Marking Information**

### (1) Package Type: SOT23 (Type S)



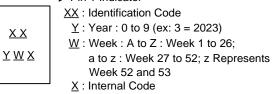
XX : Identification Code
<u>Y</u> : Year : 0 to 9 (ex: 3 = 2023)
<u>W</u> : Week : A to Z : Week 1 to 26;
a to z : Week 27 to 52; z Represents
Week 52 and 53
<u>X</u> : Internal Code

Part Number	Package	Identification Code
AH1381-SA-7		F6
AH1382-SA-7	SOT23 (Type S)	F7
AH1383-SA-7		F8

#### (2) Package Type: X2-DFN1410-4

#### (Top View)

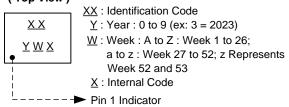
---- ► Pin 1 Indicator



Part Number	Package	Identification Code
AH1381-HK4-7		F6
AH1382-HK4-7	X2-DFN1410-4	F7
AH1383-HK4-7		F8

#### (3) Package Type: X2-DFN1010-4 (Type B)

#### (Top View)



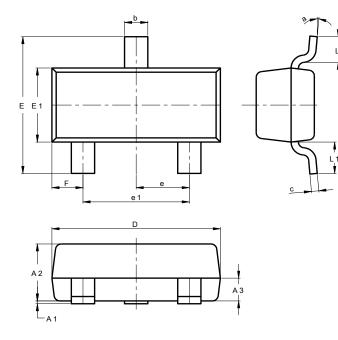
Part Number	Package	Identification Code
AH1381-FS4-7		J6
AH1382-FS4-7	X2-DFN1010-4 (Type B)	J7
AH1383-FS4-7		J8



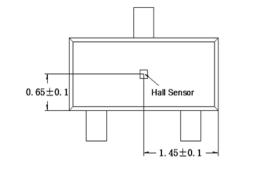
# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

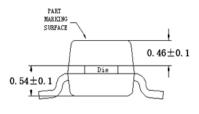
### (1) Package Type: SOT23 (Type S)



[	COT22		<u>,                                     </u>					
	SOT23 (Type S)							
Dim	Min	Max	Тур					
A1	0.013	0.10	0.05					
A2	0.90	1.025	1.00					
A3	0.375	0.425	0.40					
b	0.37	0.51	0.40					
С	0.10	0.18	0.125					
D	2.80	3.00	2.90					
E	2.30	2.50	2.40					
E1	1.20	1.40	1.30					
е	0.89	1.03	0.915					
e1	1.78	2.05	1.83					
F	0.45	0.60	0.535					
L1	0.45	0.61	0.55					
L	0.25	0.55	0.40					
а	0°	8°						
All	Dimens	ions in	mm					



TOP VIEW



Side VIEW

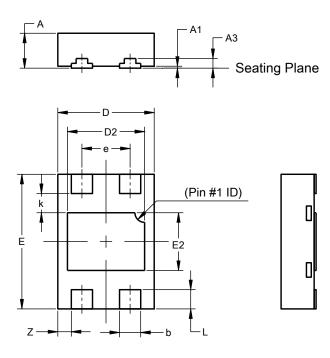
Sensor Location



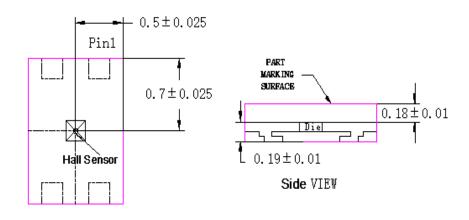
# Package Outline Dimensions (continued)

Please see http://www.diodes.com/package-outlines.html for the latest version.

### (2) Package Type: X2-DFN1410-4



X2-DFN1410-4				
Dim	Min	Max	Тур	
Α		0.40	0.37	
A1	0.00	0.05	0.02	
A3	-	-	0.100	
b	0.17	0.27	0.22	
D	0.95	1.05	1.00	
D2	0.70	0.90	0.80	
ш	1.35	1.45	1.40	
E2	0.50	0.70	0.60	
e	0.50BSC			
k			0.20	
L	0.15	0.25	0.20	
Z			0.14	
All Dimensions in mm				



TOP VIEW

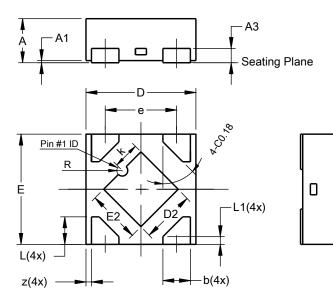
Sensor Location



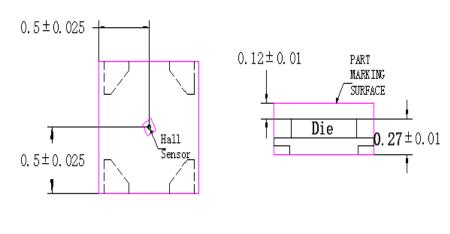
### Package Outline Dimensions (continued)

Please see http://www.diodes.com/package-outlines.html for the latest version.

### (3) Package Type: X2-DFN1010-4 (Type B)



X2-DFN1010-4 (Type B)				
Dim	Min	Max	Тур	
Α	-	0.40	0.39	
A1	0.00	0.05	0.02	
A3	-	-	0.13	
b	0.20	0.30	0.25	
D	0.95	1.05	1.00	
D2	0.43	0.53	0.48	
E	0.95	1.05	1.00	
E2	0.43	0.53	0.48	
е	-	-	0.65	
k	0.19	0.29	0.24	
L	0.20	0.30	0.25	
L1	0.02	0.12	0.07	
R	0.02	0.08	0.05	
z	-	-	0.050	
All Dimensions in mm				



TOP VIEM



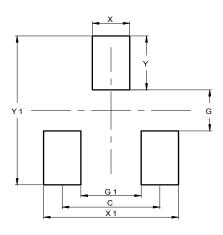
Sensor Location



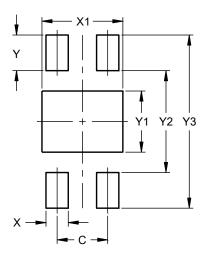
# Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

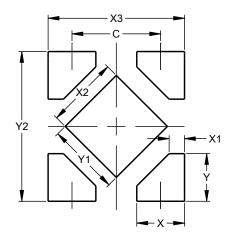
### (1) Package Type: SOT23 (Type S)



### (2) Package Type: X2-DFN1410-4



### (3) Package Type: X2-DFN1010-4 (Type B)



Dimensions	Value (in mm)
С	0.650
Х	0.350
X1	0.112
X2	0.530
X3	1.00
Y	0.350
Y1	0.530
Y2	1.100

Dimensions	Value (in mm)	
С	1.830	
G	0.800	
G1	1.130	
Х	0.700	
X1	2.530	
Ý	1.050	
Y1	2.900	

Dimensions	Value (in mm)
С	0.50
Х	0.22
X1	0.80
Y	0.35
Y1	0.60
Y2	1.00
Y3	1.70



# **Mechanical Data**

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.008 grams (Approximate)



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